







TCA9509 SCPS225D - AUGUST 2011 - REVISED APRIL 2021

TCA9509 Level-Translating I²C and SMBUS Bus Repeater

1 Features

- Two-channel bidirectional buffer
- I²C bus and SMBus compatible
- Operating supply voltage range of 2.7 V to 5.5 V on B side
- Operating voltage range of 0.9 V to 5.5 V on A side
- Voltage-level translation from 0.9 V to 5.5 V and 2.7 V to 5.5 V
- Active-high repeater-enable input
- Requires no external pullup resistors on lower-voltage port-A
- Open-drain I²C I/O
- 5.5-V Tolerant I²C and enable input support mixedmode signal operation
- Lockup-free operation
- Accommodates standard mode and fast mode I²C devices and multiple controllers
- Supports arbitration and clock stretching across Repeater
- Powered-off high-impedance I²C bus pins
- Supports 400-kHz fast I²C bus operating speeds
- Available in
 - 1.6-mm × 1.6-mm, 0.4-mm height, 0.5-mm pitch QFN package
 - 3-mm × 3-mm Industry standard MSOP package
- Latch-up performance exceeds 100 mA Per JESD 78, class II
- ESD protection exceeds JESD 22
 - 2000-V Human-body model (A114-A)
 - 1000-V Charged-device model (C101)

2 Applications

- Servers
- Routers (Telecom Switching Equipment)
- **Industrial Equipment**
- Products with many I²C targets and or long PCB Traces

3 Description

This TCA9509 integrated circuit is an I²C bus/SMBus Repeater for use in I²C/SMBus systems. It can also provide bidirectional voltage-level translation (uptranslation/down-translation) between low voltages (down to 0.9 V) and higher voltages (2.7 V to 5.5 V) in mixed-mode applications. This device enables I²C and similar bus systems to be extended, without degradation of performance even during level shifting.

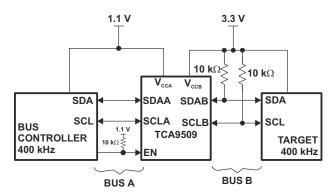
The TCA9509 buffers both the serial data (SDA) and the serial clock (SCL) signals on the I²C bus, thus allowing 400-pF bus capacitance on the B-side. This device can also be used to isolate two halves of a bus for voltage and capacitance.

The TCA9509 has two types of drivers – A-side drivers and B-side drivers. All inputs and B-side I/Os are overvoltage tolerant to 5.5 V. The A-side I/Os are overvoltage tolerant to 5.5 V when the device is unpowered (VCCB and/or VCCA = 0 V).

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
TCA9509	VSSOP (8)	3.00 mm × 3.00 mm		
TCA9509	X2QFN (8)	1.60 mm × 1.60 mm		

For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Schematic



Table of Contents

2 Applications		
3 Description		
4 Revision History		
5 Description (continued)		
6 Pin Configuration and Functions		
7 Specifications		15
7.1 Absolute Maximum Ratings		
7.2 ESD Ratings		
7.3 Recommended Operating Conditions		16
7.4 Thermal Information		
7.5 Electrical Characteristics		
7.6 Timing Requirements		
7.7 I ² C Interface Timing Requirements		
8 Parameter Measurement Information		
9 Detailed Description		
9.1 Overview	10	
	may differ from page numbers in the current version.	Dogo
Changes from Revision C (December 2017)) to Revision D (April 2021) ontroller and target in the data sheet	Page
	V_{CCB} MIN value from 0.5 mA to 0.20 mA and the TYP value	ue from
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 Changed text From: "Multiple B-sides of TO Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descripting Implementation section, Power Supply Red 	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and	Page
Changed text From: "Multiple B-sides of To Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descript Implementation section, Power Supply Red Documentation Support section, and Mechanical Section S	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and manical, Packaging, and Orderable Information section	Page
 Changed text From: "Multiple B-sides of TO Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descript Implementation section, Power Supply Red Documentation Support section, and Mechan Added junction temperature to the Absolute 	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section	Page13
 Changed text From: "Multiple B-sides of TO Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descripting Implementation section, Power Supply Red Documentation Support section, and Mechan Added junction temperature to the Absolute Changed thermal information for RVH and 	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section	Page11
 Changed text From: "Multiple B-sides of TO Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descrip Implementation section, Power Supply Red Documentation Support section, and Mech Added junction temperature to the Absolute Changed thermal information for RVH and Changed V_{ILC}, added Test Conditions with 	c Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section	Page13 table6
 Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descript Implementation section, Power Supply Red Documentation Support section, and Mech Added junction temperature to the Absolute Changed thermal information for RVH and Changed V_{ILC}, added Test Conditions with Updated Bus A (0.9-V to 5.5-V Bus) Wavef 	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section	Page131
 Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descript Implementation section, Power Supply Red Documentation Support section, and Mech Added junction temperature to the Absolute Changed thermal information for RVH and Changed V_{ILC}, added Test Conditions with Updated Bus A (0.9-V to 5.5-V Bus) Wavef 	c Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section	Page131
 Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descripting Implementation section, Power Supply Red Documentation Support section, and Mechton Added junction temperature to the Absolute Changed thermal information for RVH and Changed V_{ILC}, added Test Conditions with Updated Bus A (0.9-V to 5.5-V Bus) Wavef Updated Bus B (2.7-V to 5.5-V Bus) Wavef Changes from Revision A (October 2011) to	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section	Page13 Page1 footnotes:56 table67 Page
 Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descripting Implementation section, Power Supply Red Documentation Support section, and Mechton Added junction temperature to the Absolute Changed thermal information for RVH and Changed V_{ILC}, added Test Conditions with Updated Bus A (0.9-V to 5.5-V Bus) Wavef Updated Bus B (2.7-V to 5.5-V Bus) Wavef Changes from Revision A (October 2011) to	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section DGK packages new MIN and TYP values in the Electrical Characteristics form	Page13 Page1 footnotes:56 table67 Page
 Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descript Implementation section, Power Supply Red Documentation Support section, and Mech Added junction temperature to the Absolute Changed thermal information for RVH and Changed V_{ILC}, added Test Conditions with Updated Bus A (0.9-V to 5.5-V Bus) Wavef Updated Bus B (2.7-V to 5.5-V Bus) Wavef Changes from Revision A (October 2011) to Added DGK package and package information 	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section	Page1 table6 table77 Page
 Changes from Revision B (January 2012) to Added ESD Ratings table, Feature Descript Implementation section, Power Supply Red Documentation Support section, and Mech Added junction temperature to the Absolute Changed thermal information for RVH and Changed V_{ILC}, added Test Conditions with Updated Bus A (0.9-V to 5.5-V Bus) Wavef Updated Bus B (2.7-V to 5.5-V Bus) Wavef Changes from Revision A (October 2011) to Added DGK package and package information Changes from Revision * (August 2011) to 	o Revision C (December 2017) otion section, Device Functional Modes, Application and commendations section, Layout section, Device and nanical, Packaging, and Orderable Information section	Page156 table677 Page1
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5 Description (continued)

The bus port B drivers are compliant with SMBus I/O levels, while the A-side uses a current sensing mechanism to detect the input or output LOW signal which prevents bus lock-up. The A-side uses a 1 mA current source for pull-up and a 200 Ω pull-down driver. This results in a LOW on the A-side accommodating smaller voltage swings. The output pull-down on the A-side internal buffer LOW is set for approximately 0.2 V, while the input threshold of the internal buffer is set about 50 mV lower than that of the output voltage LOW. When the A-side I/O is driven LOW internally, the LOW is not recognized as a LOW by the input. This prevents a lock-up condition from occurring. The output pull-down on the B-side drives a hard LOW and the input level is set at 0.3 of SMBus or I²C-bus voltage level which enables B side to connect to any other I²C-bus devices or buffer.

The TCA9509 drivers are not enabled unless V_{CCA} is above 0.8 V and V_{CCB} is above 2.5 V. The enable (EN) pin can also be used to turn the drivers on and off under system control. Caution should be observed to only change the state of the EN pin when the bus is idle.



6 Pin Configuration and Functions

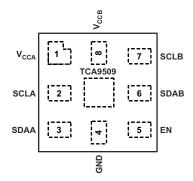


Figure 6-1. RVH Package, 8-Pin X2QFN, Top View

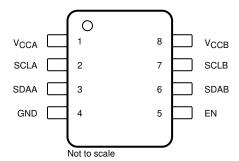


Figure 6-2. DGK Package, 8-Pin VSSOP, Top View

Table 6-1. Pin Functions

PI	PIN		DESCRIPTION
NAME	NO.	- I/O	DESCRIPTION
V _{CCA}	1	Supply	A-side supply voltage (0.9 V to 5.5 V)
SCLA	2	I/O	Serial clock bus, A side.
SDAA	3	I/O	Serial data bus, A side.
GND	4	Supply	Supply ground
EN	5	Input	Active-high repeater enable input
SDAB	6	I/O	Serial data bus, B side. Connect to V _{CCB} through a pull-up resistor.
SCLB	7	I/O	Serial clock bus, B side. Connect to V _{CCB} through a pull-up resistor.
V _{CCB}	8	Supply	B-side and device supply voltage (2.7 V to 5.5 V)
Thermal Attach Pad	-	-	Thermal Attach Pad is not electrically connected and it is recommended to be attached to GND for best thermal performance. This is for the RVH package only.

Product Folder Links: TCA9509



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

	i ü		MIN	MAX	UNIT
V _{CCB}	Supply voltage		-0.5	6	V
V _{CCA}	Supply voltage		-0.5	6	V
VI	Enable input voltage ⁽²⁾	-0.5	6	V	
V _{I/O}	I ² C bus voltage ⁽²⁾	-0.5	6	V	
I _{IK}	Input clamp current	V ₁ < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		-20	IIIA
P_d	Max power dissipation		100	mW	
T _J	Junction temperature		125	°C	
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
, Electrostatic	Electrostatic	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
V _(ESD)	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

			MIN	MAX	UNIT
V _{CCA}	Supply voltage, A-side bus		0.9 ⁽¹⁾	5.5	V
V _{CCB}	Supply voltage, B-side bus		2.7	5.5	V
V _{IH}		SDAA, SCLA	0.7 × V _{CCA}	V _{CCA}	
	High-level input voltage	SDAB, SCLB	0.7 × V _{CCB}	5.5	V
		EN	0.7 × V _{CCA}	5.5	
		SDAA, SCLA	-0.5	0.3	
V _{IL}	Low-level input voltage	SDAB, SCLB	-0.5	0.3 × V _{CCB}	V
		EN	-0.5	0.3 × V _{CCA}	
	Low lovel output ourrent	SDAA, SCLA		10	μA
I _{OL}	Low-level output current	SDAB, SCLB		6	mA
T _A	Operating free-air temperature		-40	85	°C

(1) Low-level supply voltage

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Thermal Information

		TCA9509			
	THERMAL METRIC(1)	RVH (X2QFN)	DGK (VSSOP)	UNIT	
		8 PINS	8 PINS		
R _{0JA}	Junction-to-ambient thermal resistance ⁽²⁾	160.3	222.9	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	66.4	109.5	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	115.9	144.5	°C/W	
ΨЈТ	Junction-to-top characterization parameter	0.8	34.5	°C/W	
ΨЈВ	Junction-to-board characterization parameter	116.2	142.7	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	80.5	n/a	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

7.5 Electrical Characteristics

 $V_{CCB} = 2.7 \text{ V}$ to 5.5 V, $V_{CCA} = 0.9 \text{ V}$ to $(V_{CCB}-1)$, $T_A = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IK}	Input clamp voltage		I _I = -18 mA	-1.5		-0.5	V
V _{OL}	Low-level output voltage	SDAA, SCLA	$\begin{split} I_{OL} &= 10 \; \mu A, \\ V_{ILA} &= V_{ILB} = 0 \; V, \\ V_{CCA} &= 0.9 \; to \; 1.2 \; V \end{split}$		0.18	0.25	V
VOL	Low-level output voltage	SDAA, SCLA	$I_{OL} = 20 \mu A,$ $V_{ILA} = V_{ILB} = 0 V,$ $1.2V < V_{CCA} \le (V_{CCB} - 1 V)$		0.2	0.3	V
V _{OL} – V _{ILc}	Low-level input voltage below low-level output voltage	SDAA, SCLA			50		mV
V _{ILc}	SDA and SCL low-level input	SDAA, SCLA	V _{CCA} ≥ 1.5 V and V _{CCB} ≥ 3.15 V	110	150		mV
	voltage contention	SDAA, SCLA	V _{CCA} < 1.5 V or V _{CCB} < 3.15 V	50	100		mv
V _{OLB}	Low-level output voltage	SDAB, SCLB	I _{OL} = 6 mA		0.1	0.2	V
	Quiescent supply current for V ₀		All port A Static high	0.25	0.45	0.9	mΛ
I _{CC}	Quiescent supply current for v_0	CCA	All port A Static low	1.25			mA
I _{CC}	Quiescent supply current for Vo	CCB	All port B Static high	0.2	0.5	1.1	mA
		SDAB, SCLB	V _I = V _{CCB}			±1	
		SDAB, SCLB	V _I = 0.2 V			10	
	Input leakage current	SDAA, SCLA	V _I = V _{CCA}			±1	
I _I	iliput leakage culterit	SDAA, SCLA	V _I = 0.2 V			10	μA
		EN	V _I = V _{CCB}			±1	
		EN	V _I = 0.2 V			-10	
1	High-level output leakage	SDAB, SCLB	V _O = 3.6 V			10	^
I _{OH}	current	SDAA, SCLA	V ₀ = 3.0 V			10	μA
C _{IOA}	I/O capacitance of A-side	SCLA, SDAA	V _I = 0 V	-	6.5	7	pF
C _{IOB}	I/O capacitance of B-side	SCLB, SDAB	V _I = 0 V	5.5		6.2	pF

Product Folder Links: TCA9509

⁽²⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



7.6 Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
t _{su}	Setup time, EN high before Start condition ⁽¹⁾	100		ns
t _h	Hold time, EN high after Stop condition ⁽¹⁾	100		ns

(1) EN should change state only when the global bus and the repeater port are in an idle state.

7.7 I²C Interface Timing Requirements

 $T_{\Delta} = -40$ °C to 85°C (unless otherwise noted)

	PARAMETE	:R	V _{CCA} (INPUT)	V _{CCB} (OUTPUT)	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PHL}	Propagation delay	port A to port B	1.9 V	5 V	EN High	123.1	127.2	132.8	ns
		port B to port A	1.9 V	5 V	EN Fligh	88.1	88.8	89.8	
t _{PLH}	Dranagation dalay	port A to port B	1.9 V	5 V	TN Himb	122.6	125.7	131.7	
Propagation d	Propagation delay	port B to port A	1.9 V	5 V	EN High	123	124.1	126.9	ns
	Transition time	port A	1.9 V	5 V	EN High	40.1	40.9	41.9	
t _{rise} Tr	transidon dine	port B	1.9 V	5 V		57.3	57.5	58.4	ns
	Transition time	port A	4.0.1/	5 V	EN High	14.5	16.4	17.9	
t _{fall}		port B	1.9 V	5 V	Livingii	18.7	19.4	20.2	ns
t _{PLH2}	Propagation delay 50% of initial low on Port A to 1.5 V on Port B	port A to port B	1.9 V	5 V		176	177.3	178	ns
f _{MAX}	Maximum switching frequency					400			KHz

(1) Typical values were measured with $V_{CCA} = V_{CCB} = 2.7 \text{ V}$ at $T_A = 25 ^{\circ}\text{C}$, unless otherwise noted.

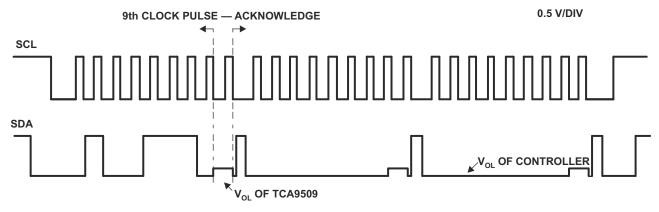


Figure 7-1. Bus A (0.9-V to 5.5-V Bus) Waveform



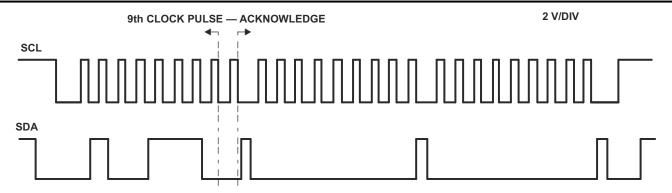
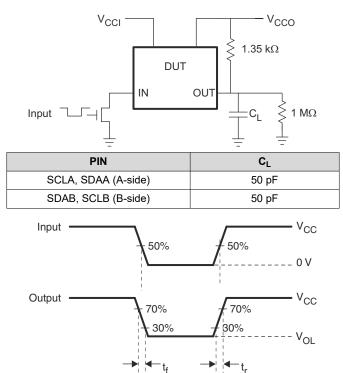


Figure 7-2. Bus B (2.7-V to 5.5-V Bus) Waveform



8 Parameter Measurement Information



- R_T termination resistance should be equal to Z_{OUT} of pulse generators.
- B. C_L includes probe and jig capacitance.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, slew rate \geq 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 8-1. Test Circuit and Voltage Waveforms



9 Detailed Description

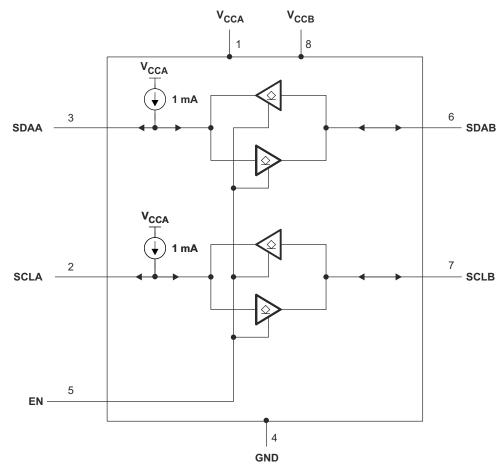
9.1 Overview

This TCA9509 integrated circuit is an I^2C bus/SMBus Repeater for use in I^2C /SMBus systems. It can also provide bidirectional voltage-level translation (up-translation/down-translation) between low voltages (down to 0.9 V) and higher voltages (2.7 V to 5.5 V) in mixed-mode applications. This device enables I^2C and similar bus systems to be extended, without degradation of performance even during level shifting.

The TCA9509 buffers both the serial data (SDA) and the serial clock (SCL) signals on the I²C bus, thus allowing 400-pF bus capacitance on the B-side. This device can also be used to isolate two halves of a bus for voltage and capacitance.

The TCA9509 has two types of drivers – A-side drivers and B-side drivers. All inputs and B-side I/O's are overvoltage tolerant to 5.5V. The A-side I/O's are overvoltage tolerant to 5.5 V when the device is unpowered $(V_{CCB} = 0V)$.

9.2 Functional Block Diagram



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9.3 Feature Description

9.3.1 Two-Channel Bidirectional Buffer

The TCA9509 is a two-channel bidirectional buffer with level-shifting capabilities, featuring an integrated current source on the A-side.

9.3.2 Integrated A-Side Current Source

The A-side ports of the TCA9509 feature an integrated 1 mA current source, eliminating the need for external pull-up resistors on SDAA and SCLA.

9.3.3 Standard Mode and Fast Mode Support

The TCA9509 supports standard mode as well as fast mode I²C. The maximum system operating frequency will depend on system design and delays added by the repeater.

9.4 Device Functional Modes

Table 9-1 lists the functional modes for the TCA9509.

Table 9-1. Function Table

INPUT EN	FUNCTION
L	Outputs disabled
Н	SDAA = SDAB SCLA = SCLB



10 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

10.1 Application Information

The TCA9509 is 5-V tolerant, so it does not require any additional circuitry to translate between 0.9-V to 5.5-V bus voltages and 2.7-V to 5.5-V bus voltages.

When the B-side of the TCA9509 is pulled low by a driver on the I^2C bus and the falling edge goes below 0.3 V_{CCB} , it causes the internal driver on the A-side to turn on, causing the A-side to pull down to about 0.2 V_{CCB} . When the A-side of the TCA9509 falls, a comparator detects the falling edge and causes the internal driver on the B-side to turn on and pull the B-side pin down to ground. In order to illustrate what would be seen in a typical application, refer to Figure 7-1. If the bus controller in Figure 10-1 were to write to the target through the TCA9509, waveforms shown in Figure 7-2 would be observed on the B bus. This looks like a normal I^2C bus transmission, except that the high level may be as low as 0.9 V_{CCB} , and the turn on and turn off of the acknowledge signals are slightly delayed.

On the A-side bus of the TCA9509, the clock and data lines would have a positive offset from ground equal to the V_{OL} of the TCA9509. After the eighth clock pulse, the data line is pulled to the V_{OL} of the controller device, which is close to ground in this example. At the end of the acknowledge, the level rises only to the low level set by the driver in the TCA9509 for a short delay, while the B-bus side rises above 0.3 V_{CCB} and then continues high. It is important to note that any arbitration or clock stretching events require that the low level on the A-bus side at the input of the TCA9509 (V_{IL}) be at or below V_{ILC} to be recognized by the TCA9509 and then transmitted to the B-bus side.

10.2 Typical Application

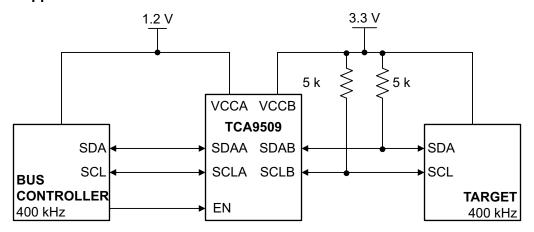


Figure 10-1. Typical Application, A-side Connected to controller

10.2.1 Design Requirements

A typical application is shown in Figure 10-1. In this example, the system controller is running on a 1.2-V I^2C bus, and the target is connected to a 3.3-V bus. Both buses run at 400 kHz. Controller devices can be placed on either bus. For the level translating application, the following should be true: $V_{CCA} \le (V_{CCB} - 1 \text{ V})$

- $V_{CCA} = 0.9 \text{ V to } 5.5 \text{ V}$
- V_{CCB} = 2.7 to 5.5 V
- A-side ports must not be connected together
- Pullup resistors should not be placed on the A-side ports

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10.2.2 Detailed Design Procedure

10.2.2.1 Clock Stretching Support

The TCA9509 can support clock stretching, but care needs to be taken to minimize the overshoot voltage presented during the hand-off between the target and controller. This is best done by increasing the pull-up resistor value on B-side ports.

10.2.2.2 V_{ILC} and Pulldown Strength Requirements

For the TCA9509 to function correctly, all devices on the A-side must be able to pull the A-side below the voltage input low contention level (V_{ILC}). This means that the V_{OL} of any device on the A-side must be below V_{ILC} min.

The V_{OL} can be adjusted by changing the I_{OL} through the device which is set by the pull-up resistance value. The pull-up resistance on the A-side must be carefully selected to ensure that the logic levels will be transferred correctly to the B-side.

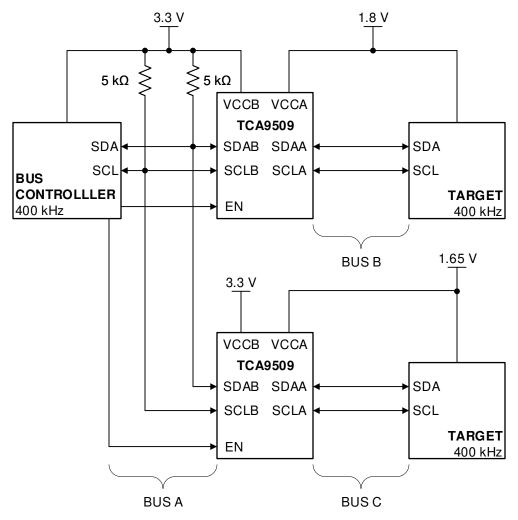


Figure 10-2. Typical Star Application

Multiple B-sides of TCA9509 can be connected in a star configuration, allowing all nodes to communicate with each other. The A-sides should not be connected together when used in a star/parallel configuration.



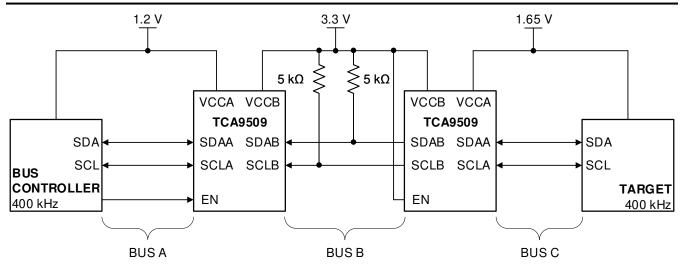


Figure 10-3. Typical Series Application, Two B-Sides Connected Together

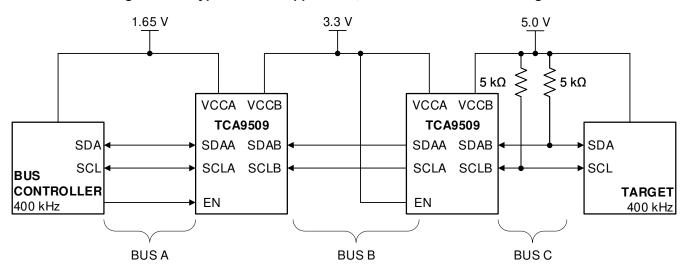


Figure 10-4. Typical Series Application, A-side Connected to B-Side

To further extend the I^2C bus for long traces/cables, multiple TCA9509 devices can be connected in series as long as the A-side is connected to the B-side and $V_{CCA} \le (V_{CCB} - 1 \text{ V})$ must also be met. Series connections can also be made by connecting both B-sides together while following power supply rule $V_{CCA} \le (V_{CCB} - 1 \text{ V})$. I^2C bus target devices can be connected to any of the bus segments. The number of devices that can be connected in series is limited by repeater delay/time-of-flight considerations on the maximum bus speed requirements.



11 Power Supply Recommendations

 V_{CCB} and V_{CCA} can be applied in any sequence at power up. The TCA9509 includes a power-up circuit that keeps the output drivers turned off until V_{CCB} is above 2.5 V and the V_{CCA} is above 0.8 V. After power up and with the EN high, a low level on the B-side (below $0.3 \times V_{CCB}$) turns the corresponding A-side driver (either SDA or SCL) on and drives the A-side down to approximately 0.2 V. When the B-side rises above $0.3 \times V_{CCB}$, the A-side pull-down driver is turned off and the external pull-up resistor pulls the pin high. When the A-side falls first and goes below $0.3 \times V_{CCA}$, the B-side driver is turned on and the B-side pulls down to 0 V. The A-side pull-down is not enabled unless the A-side voltage goes below 0.4 V. If the A-side low voltage does not go below 0.5 V, the B-side driver turns off when the A-side voltage is above $0.7 \times V_{CCA}$. If the A-side low voltage goes below 0.4 V, the A-side pull-down driver is enabled, and the A-side is able to rise to only 0.5 V until the B-side rises above $0.3 \times V_{CCB}$.

A 100 nF a decoupling capacitor should be placed as close to the V_{CCA} and V_{CCB} pins in order to provide proper filtering of supply noise.



12 Layout

12.1 Layout Guidelines

There are no special layout procedures required for the TCA9509.

It is recommended that the decoupling capacitors be placed as close to the VCC pins as possible.

12.2 Layout Example

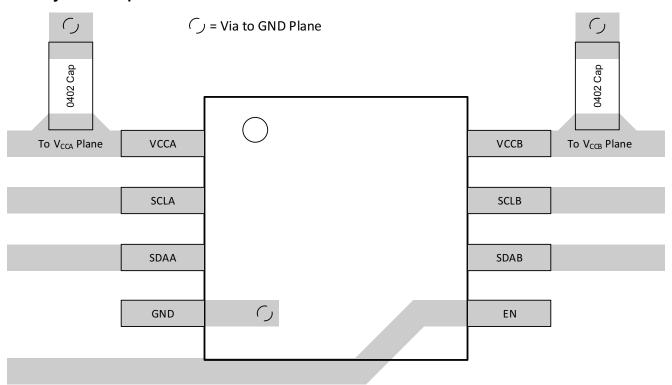


Figure 12-1. Example Layout



13 Device and Documentation Support

13.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

13.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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13.3 Trademarks

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All trademarks are the property of their respective owners.

13.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

13.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 1-Nov-2022

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
TCA9509DGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAUAG SN	Level-1-260C-UNLIM	-40 to 85	(7KO, 7KQ)	Samples
TCA9509MRVHR	ACTIVE	X2QFN	RVH	8	5000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	7K	Samples
TCA9509RVHR	ACTIVE	X2QFN	RVH	8	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	7K	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 13-Apr-2024

TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TCA9509MRVHR	X2QFN	RVH	8	5000	180.0	8.4	1.8	1.8	0.5	4.0	8.0	Q1
TCA9509RVHR	X2QFN	RVH	8	5000	180.0	8.4	1.8	1.8	0.5	4.0	8.0	Q3

PACKAGE MATERIALS INFORMATION

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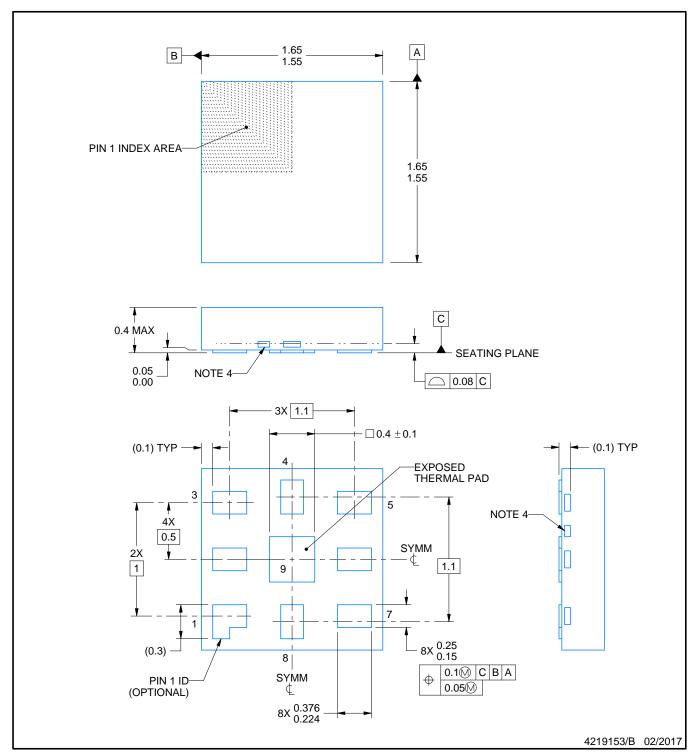


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TCA9509MRVHR	X2QFN	RVH	8	5000	183.0	183.0	20.0
TCA9509RVHR	X2QFN	RVH	8	5000	202.0	201.0	28.0



PLASTIC QUAD FLATPACK - NO LEAD

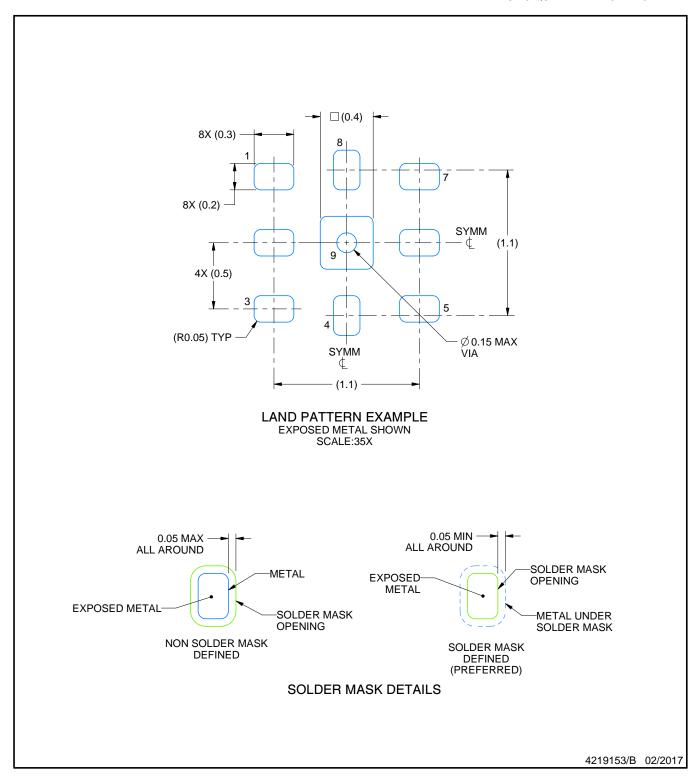


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
- 4. Exposed tie bars may vary in size and location.



PLASTIC QUAD FLATPACK - NO LEAD

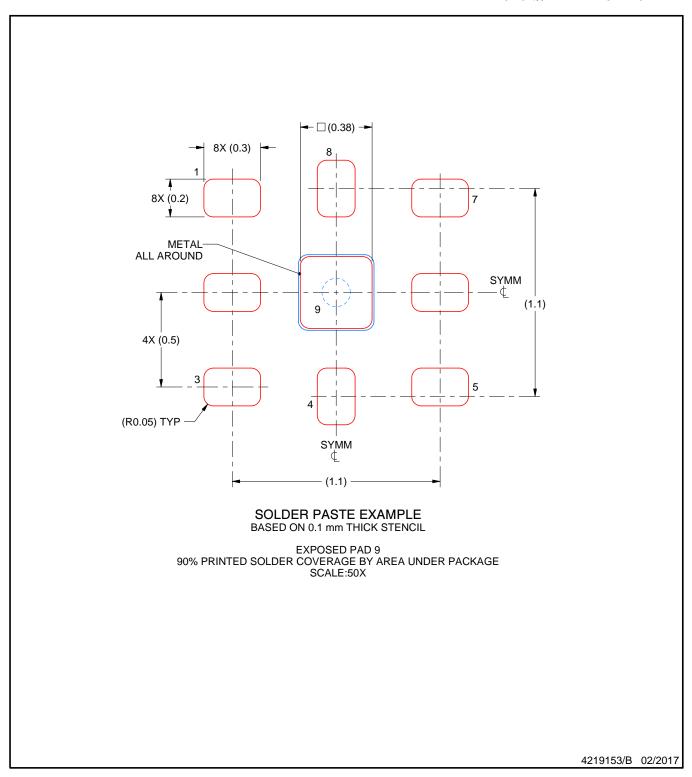


NOTES: (continued)

- 5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 6. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



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